

Clairex CLA101 Phototransistor Array Datasheet

<http://www.manuallib.com/clairex/cla101-phototransistor-array-datasheet.html>

The CLA101 four channel phototransistor array can be custom designed with photodiode or photo-IC chips. An emitter version is also available using same wavelength or different wavelength die. For additional information, call Clairex.

ManualLib.com collects and classifies the global product instruction manuals to help users access anytime and anywhere, helping users make better use of products.

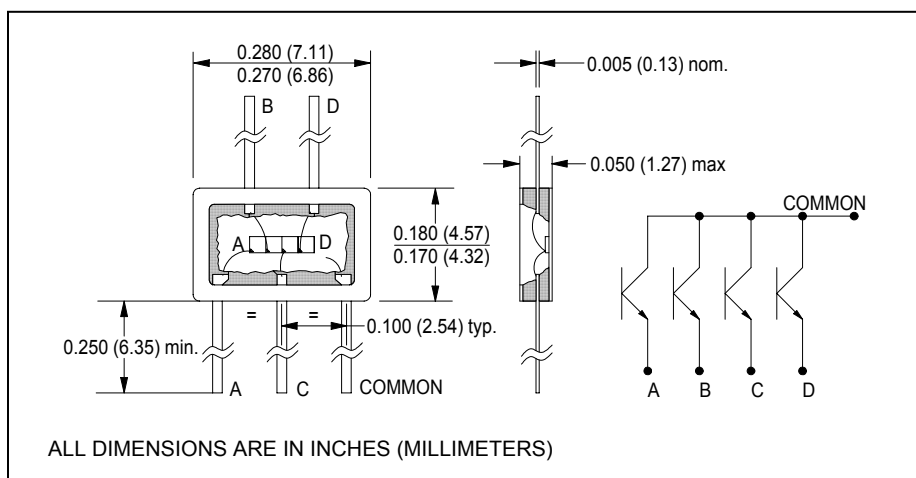
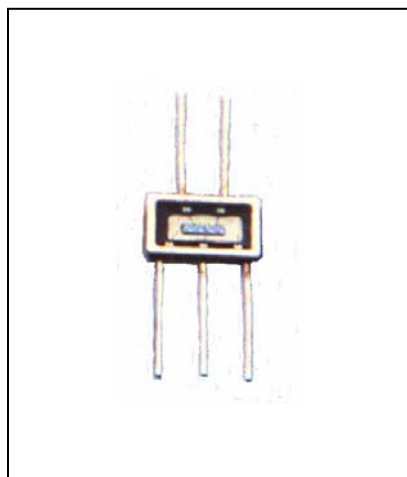
<http://www.manuallib.com>

CLA101

Four Channel Phototransistor Array



September, 2001



features

- Full range of sensor chips
- Full range of emitter chips
- Miniature surface mountable package

description

The CLA101 four channel phototransistor array can be custom designed with photodiode or photo-IC chips. An emitter version is also available using same wavelength or different wavelength die. For additional information, call Clairex.

absolute maximum ratings ($T_A = 25^\circ\text{C}$ unless otherwise stated)

storage temperature	-40°C to +100°C
operating temperature	-40°C to +100°C
lead soldering temperature ⁽¹⁾	260°C
maximum continuous current ⁽²⁾	50mA
peak forward current (1.0ms pulse width, 10% duty cycle)	1A
reverse voltage	5V
continuous power dissipation ⁽³⁾	75mW

notes:

1. At the base of the header for 5 seconds maximum.
2. Derate linearly 0.53mA/°C from 25°C free air temperature to $T_A = +100^\circ\text{C}$.
3. Derate linearly 0.80mW/°C from 25°C free air temperature to $T_A = +100^\circ\text{C}$.

electrical characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

symbol	parameter	min	typ	max	units	test conditions
I_L	Light current ⁽⁴⁾	150	-	-	μA	$E_e = 1\text{mW}/\text{cm}^2$, $V_{CE} = 5\text{V}$
	Matching factor	-	-	0.4	-	$(I_{L\text{HIGH}} - I_{L\text{LOW}})/I_{L\text{HIGH}}$
I_D	Dark current	-	-	100	nA	$V_{CE} = 10\text{V}$, $H=0$
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	40	-	-	V	$I_{CE} = 0.1\text{mA}$
$V_{(BR)ECO}$	Emitter-collector breakdown voltage	5.0	-	-	V	$I_{EC} = 0.1\text{mA}$
$V_{CE(SAT)}$	Collector-emitter saturation voltage	-	-	0.4	V	$E_e = 20\text{mW}/\text{cm}^2$, $I_{CE} = 0.5\text{mA}$
t_r, t_f	Rise and fall times	-	3.0	-	μs	$R_L = 100\Omega$, $V_{CE} = 5\text{V}$

Note: 4. Radiation source for light current testing is tungsten at 2854°K.

Clairex reserves the right to make changes at any time to improve design and to provide the best possible product.

Revised 3/15/06

Clairex Technologies, Inc.
Phone: 972-265-4900

1301 East Plano Parkway
Fax: 972-265-4949

Plano, Texas 75074-8524
www.clairex.com